











### TPS79718, TPS797285, TPS79730, TPS79733

SLVS332J - MARCH 2001 - REVISED DECEMBER 2016

# TPS797xx Ultra-Low I<sub>O</sub>, 50-mA Low-Dropout Linear Regulators With Power Good Output in SC70 Package

#### **Features**

- 50-mA Low-Dropout Regulator
- Ultra-Low 1.2-µA Quiescent Current at 10 mA
- 5-Pin SC70 (DCK) Package
- Integrated Power Good Output
- Stable With Any Capacitor Greater Than 0.47 µF
- Typical Dropout Voltage of 105 mV at 10 mA (TPS79733)
- **Over-Current Limitation**
- Operating Junction Temperature Range of -40°C to 85°C

# **Applications**

Battery-Powered Microcontrollers and Microprocessors

# 3 Description

The TPS797xx family of low-dropout voltage regulators (LDOs) offers the benefits of low-dropout voltage and ultra-low-power operation. The device is stable with any capacitor greater than 0.47-µF. Therefore, implementations of this device require very little board space due to the miniaturized packaging and potentially small output capacitor. In addition, the family includes an integrated open drain active-high power good (PG) output. Intended for use in microcontroller-based, battery-powered applications, the TPS797xx family low dropout and ultra-low-power operation result in a significant increase in system battery operating life. The small packaging minimizes consumption of board space.

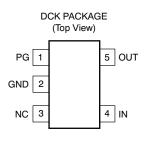
The device is enabled when the applied voltage exceeds the minimum input voltage. The usual PNP pass transistor has been replaced by a PMOS pass element. Because the PMOS pass element behaves as a low-value resistor, the dropout voltage is very low (typically, 105 mV at 10-mA of load current), and is directly proportional to the load current. The quiescent current is ultra-low (1.2-µA, typically) and is stable over the entire range of output load current (0 mA to 50 mA). When properly configured with a pullup resistor, the PG output can implement a power-on reset or low-battery indicator.

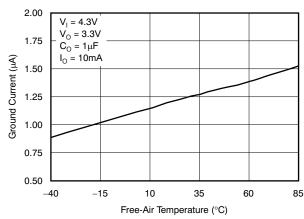
## Device Information<sup>(1)</sup>

PART NUMBER	PACKAGE	BODY SIZE (NOM)
TPS797xx	SC70 (5)	2.00 mm × 1.25 mm

<sup>(1)</sup> For all available packages, see the orderable addendum at the end of the data sheet.

# **Ground Current vs Free-Air Temperature**







# **Table of Contents**

1	Features 1	8 Application and Implementation 1
2	Applications 1	8.1 Application Information 1
3	Description 1	8.2 Typical Application1
4	Revision History2	9 Power-Supply Recommendations 1
5	Pin Configuration and Functions 4	10 Layout 1
6	Specifications4	10.1 Layout Guidelines 1
•	6.1 Absolute Maximum Ratings 4	10.2 Layout Example 1
	6.2 ESD Ratings	10.3 Power Dissipation and Junction Temperature 1
	6.3 Recommended Operating Conditions	11 Device and Documentation Support 1
	6.4 Thermal Information	11.1 Related Links 1
	6.5 Electrical Characteristics	11.2 Receiving Notification of Documentation Updates 1
	6.6 Typical Characteristics	11.3 Community Resources 1
7	Detailed Description9	11.4 Trademarks1
	7.1 Overview	11.5 Electrostatic Discharge Caution 1
	7.2 Functional Block Diagram9	11.6 Glossary 1
	7.3 Feature Description	12 Mechanical, Packaging, and Orderable
	7.4 Device Functional Modes9	Information 1

# 4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

CI	hanges from Revision I (October 2013) to Revision J	Page
•	Added ESD Ratings table, Feature Description section, Device Functional Modes, Application and Implementation section, Power Supply Recommendations section, Layout section, Device and Documentation Support section, and Mechanical, Packaging, and Orderable Information section	
•	Deleted Dissipation Ratings table; see Thermal Information table	4
•	Added Thermal Information table	5
•	Changed Load Regulation parameter unit From: mV To: %/A	
•	Changed Output Spectral Noise Density vs Frequency graph Y-axis unit From: nV/√Hz To: μV/√Hz	<mark>7</mark>
•	Changed IOUTx values From: I <sub>CL</sub> To: I <sub>SC</sub>	9
·	Changed Dropout Voltage vs Junction Temperature graph Y-axis unit From: V To: mV (typo)hanges from Revision G (November 2009) to Revision H	8
•	Deleted sentence regarding thermal protection	12
CI	hanges from Revision F (May 2009) to Revision G	Page
•	Changed document title	1
•	Deleted references to SOT323 package throughout document	1
•	Changed Test Conditions for Electrical Characteristics table	5
•	Changed output voltage accuracy test conditions from 10 $\mu$ A < $I_{OUT}$ < 10 mA to 1 mA < $I_{OUT}$ < 10 mA	5

Submit Documentation Feedback

Copyright © 2001–2016, Texas Instruments Incorporated

Changed PG trip threshold voltage test conditions from  $V_{OUT}$  decreasing to  $V_{OUT}$  increasing; deleted minimum and



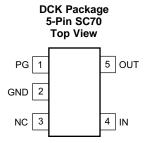
#### www.ti.com

SLVS332J-MARCH 2001-REVISED DECEMBER 2016

Submit Documentation Feedback



# 5 Pin Configuration and Functions



#### **Pin Functions**

PIN		1/0	DESCRIPTION	
NO.	NAME	- I/O	DESCRIPTION	
1	PG	0	The PG pin for the fixed voltage option devices is an open drain, active-high output that indicates the status of $V_O$ (output of the LDO). When $V_O$ exceeds approximately 90% of the regulated voltage, PG goes to a high-impedance state. PG goes to a low-impedance state when $V_O$ falls below approximately 90% (that is, overload condition) of the regulated voltage. The open drain output of the PG pin requires a pullup resistor.	
2	GND	_	Ground	
3	NC	_	No connection	
4	IN	I	The IN pin is the power-supply input to the device.	
5	OUT	0	The OUT pin provides the regulated output voltage of the device.	

# 6 Specifications

# 6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted) (1)

		MIN	MAX	UNIT
Voltage	Input voltage <sup>(2)</sup>	-0.3	6	V
	Maximum dc output voltage		4.9	V
Current	Peak output current	Internal	Internally limited	
Temperature	Operating virtual junction temperature, T <sub>J</sub>	-40	85	°C
	Storage temperature, T <sub>stg</sub>	-65	150	°C

<sup>(1)</sup> Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

# 6.2 ESD Ratings

			VALUE	UNIT
V	Floatroototic disabores	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 (1)	±2000	V
V <sub>(ESD)</sub>	Electrostatic discharge	Charged-device model (CDM), per JEDEC specification JESD22-C101 <sup>(2)</sup>	±500	V

<sup>(1)</sup> JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

Submit Documentation Feedback

<sup>(2)</sup> All voltage values are with respect to network ground pin.

<sup>(2)</sup> JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



# 6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
$V_{I}$	Input voltage	1.8		5.5	V
Vo	Output voltage	1.8		3.3	V
Io	Output current	0		50	mA
C <sub>I</sub>	Input capacitor	0	0.1		μF
Co	Output capacitor	0.47	1		μF
TJ	Junction temperature	-40		85	°C

# 6.4 Thermal Information

		TPS797xx	
	THERMAL METRIC <sup>(1)</sup>	DCK (SC70)	UNIT
		5 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	230.9	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	98.3	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	70.7	°C/W
ΨЈТ	Junction-to-top characterization parameter	3.9	°C/W
ΨЈВ	Junction-to-board characterization parameter	70.1	°C/W
R <sub>0</sub> JC(bot)	Junction-to-case (bottom) thermal resistance	_	°C/W

<sup>(1)</sup> For more information about traditional and new thermal metrics, see Semiconductor and IC Package Thermal Metrics (SPRA953).

## 6.5 Electrical Characteristics

over operating temperature range  $T_J = -40^{\circ}C$  to 85°C, typical values are at  $T_A = 25^{\circ}C$ ,  $V_I = V_{O~(typ)} + 0.5$  V or 2 V (whichever is greater);  $I_O = 0.5$  mA,  $V_{SET}$ ,  $V_{EN} = V_I$ , and  $C_O = 1$   $\mu F$  (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
V	Input voltage <sup>(1)</sup>	$I_O = 3 \text{ mA}$	1.8		5.5	V
VI	input voitage 7	$I_O = 10 \text{ mA}$	2		5.5	V
Io	Continuous output current <sup>(2)</sup>		0		50	mA
Vo	Output voltage accuracy <sup>(3)</sup>	$V_O + 1 \ V \le V_I \le 5.5 \ V$ 1 mA < $I_O < 10 \ mA$	-4%		4%	
$\Delta V_{O(\Delta VI)}$	Line regulation (3)	$V_{O} + 1 \ V \le V_{I} \le 5.5 \ V$		0.15%		V
$\Delta V_{O(\Delta IO)}$	Load regulation	1 μA < I <sub>O</sub> < 10 mA		5%		Α
\/	Dropout voltage $^{(4)}$ , $I_O = 10$ mA $V_I = V_{O(NOM)} - 0.1$ V	TPS79730		110	200	m\/
$V_{(DO)}$		TPS79733		105	200	mV
I <sub>SC</sub>	Output current limit	V <sub>O</sub> = 0 V		190	300	mA
I <sub>(GND)</sub>	Ground pin current <sup>(3)</sup>	$I_O = 10 \text{ mA}$		1.2	2	μΑ
PSRR	Power-supply rejection ratio (ripple rejection)	$f$ = 100 Hz, $C_O$ = 10 $\mu$ F, $I_O$ = 10 mA		50		dB
V <sub>n</sub>	Output noise voltage (TPS79718)	BW = 200 kHz to 100 kHz, $C_O = 10 \mu F$ , $I_O = 10 mA$		600		$\mu V_{RMS}$
V <sub>Imin(PG)</sub>	Minimum input voltage for valid PG	$V_{(PG)} \ge 0.8 \text{ V}, I_{PG} = 100  \mu\text{A}$		1.2		V
$V_{\text{IT}}$	PG trip threshold voltage	V <sub>OUT</sub> increasing		90%		$V_{OUT}$
$V_{OL(PG)}$	PG output low voltage	$V_{I} = 1.4 \text{ V}, I_{PG} = 30  \mu\text{A}, I_{O} = 1  \text{mA}$		0.14	0.225	V
I <sub>lkg(PG)</sub>	PG leakage current	$V_{(PG)} = 5 \text{ V}, V_I = V_O + 1 \text{ V},$ $I_O = 1 \text{ mA}$	0.1			nA

<sup>(1)</sup> Minimum  $V_1 = V_0 + V_{(DO)}$  or the minimum value specified here, whichever is greater.

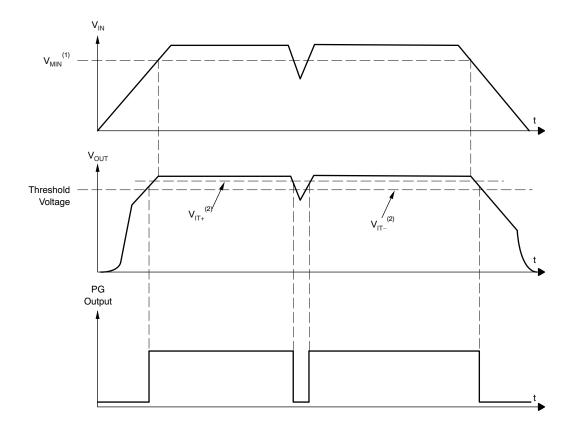
Copyright © 2001–2016, Texas Instruments Incorporated

<sup>(2)</sup> Continuous output current is limited by internal protection circuitry, but it is not recommended that the device operate above this maximum for extended periods of time.

<sup>(3)</sup> Minimum V<sub>I</sub> is specified in <sup>(1)</sup>.

<sup>(4)</sup>  $V_{(DO)}$  is not measured for the TPS79718 because minimum  $V_1 > 1.7 \text{ V}$ .





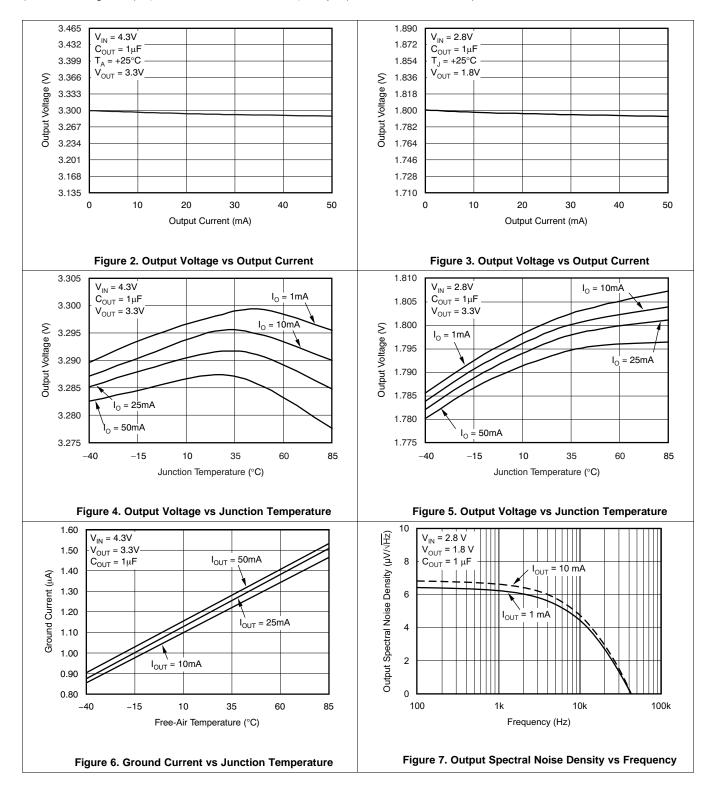
NOTES: (1)  $V_{MIN} = V_{OUT} + V_{DO}$ . (2) The PG trip voltage is typically 10% lower than the output voltage (90%  $V_{O}$ ).  $V_{IT_{+}}$  to  $V_{IT_{-}}$  is the hysteresis voltage.

Figure 1. TPS797xx PG Timing Diagram



# 6.6 Typical Characteristics

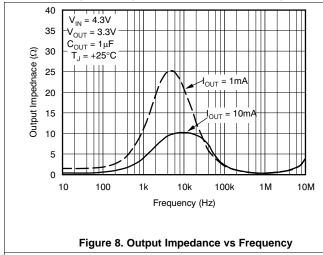
over operating temperature range  $T_J = -40^{\circ}\text{C}$  to 85°C, typical values are at  $T_A = 25^{\circ}\text{C}$ ,  $V_I = V_O$  (typical) + 0.5 V or 2 V (whichever is greater);  $I_O = 0.5$  mA,  $V_{EN} = V_I$ , and  $C_O = 1$   $\mu\text{F}$  (unless otherwise noted).

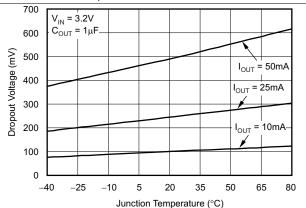




# **Typical Characteristics (continued)**

over operating temperature range  $T_J = -40^{\circ}\text{C}$  to 85°C, typical values are at  $T_A = 25^{\circ}\text{C}$ ,  $V_I = V_O$  (typical) + 0.5 V or 2 V (whichever is greater);  $I_O = 0.5$  mA,  $V_{EN} = V_I$ , and  $C_O = 1$   $\mu\text{F}$  (unless otherwise noted).







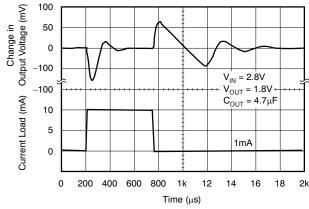


Figure 10. TPS79718 Load Transient Response

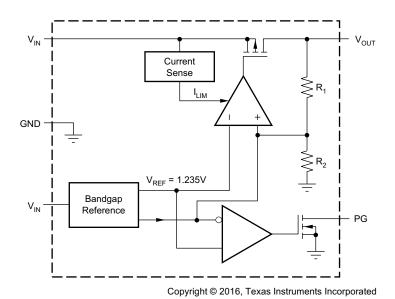


# 7 Detailed Description

#### 7.1 Overview

The TPS797xx devices offer a low-dropout voltage, ultra-low-power operation, and are stable with any capacitor greater than 0.47 µF, and contains an integrated open-drain power good (PG) output.

## 7.2 Functional Block Diagram



# 7.3 Feature Description

#### 7.3.1 Regulator Protection

The TPS797xx PMOS-pass transistor has a built-in back diode that conducts reverse current when the input voltage drops below the output voltage (for example, during power down). Current is conducted from the output to the input and is not internally limited. If extended reverse voltage operation is anticipated, external limiting might be appropriate.

The TPS797xx features internal current limiting. During normal operation, the TPS797xx limits output current to approximately 190 mA. When current limiting engages, the output voltage scales back linearly until the overcurrent condition ends. Take care not to exceed the power dissipation ratings of the package.

#### 7.4 Device Functional Modes

Table 1 provides a quick comparison between the normal, dropout, and disabled modes of operation.

**Table 1. Device Modes Comparison** 

OPERATING MODE	PARAMETER			
OPERATING MODE	V <sub>I</sub>	I <sub>OUTx</sub>		
Normal <sup>(1)</sup>	$V_I > V_O + V_{(DO)}$	I <sub>OUTx</sub> < I <sub>SC</sub>		
Dropout <sup>(1)</sup>	$V_I < V_O + V_{(DO)}$	I <sub>OUTx</sub> < I <sub>SC</sub>		

(1) All table conditions must be met.



# 8 Application and Implementation

#### NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

# 8.1 Application Information

The TPS797xx family of low-dropout (LDO) regulators are optimized for micropower applications. The family features extremely low dropout voltages and ultra-low quiescent current (typically 1.2-µA).

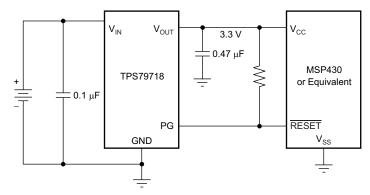
## 8.2 Typical Application

## 8.2.1 Powering Microcontrollers

This device is suited to provide a regulated input voltage and power good (PG) supervisory signal to low-power devices such as mixed-signal microcontrollers. The quiescent (or ground) current of the TPS797xx family is typically 1.2  $\mu$ A, even at full load; therefore, the reduction in battery life by including the TPS797xx in the system is negligible.

Figure 11 shows an application where the TPS79718 powers TI's MSP430 mixed signal microcontroller.

Minimal board space is required to accommodate the DCK (SC70) packaged TPS79718, the 0.1-μF output capacitor, the 0.47-μF input capacitor, and the pullup resistor on the PG pin.



Copyright © 2016, Texas Instruments Incorporated

Figure 11. MSP430 Microcontroller Powered by the TPS79718 Regulator Diagram

#### 8.2.1.1 Design Requirements

Table 2 lists the design parameters for this example.

**Table 2. Design Parameters** 

PARAMETER	VALUE
Input voltage range	3.5 V to 5.5 V
Output voltage	3.3 V
Output current rating	50 mA
Minimum output capacitor	0.47 μF

Submit Documentation Feedback



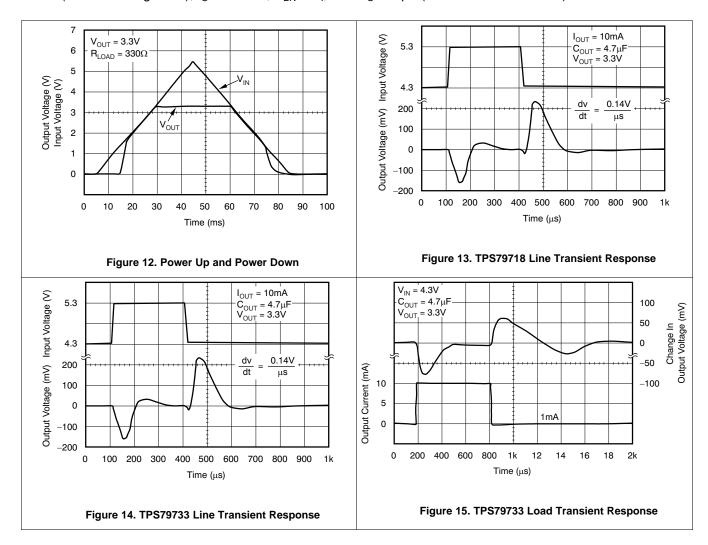
## 8.2.1.2 Detailed Design Procedure

#### 8.2.1.2.1 External Capacitor Requirements

Although not required, an input bypass capacitor with a value of  $0.1-\mu F$  or larger (connected between IN and GND and placed close to the TPS797xx) is recommended, especially when a highly resistive power supply is powering the LDO in addition to other devices. Like all low-dropout regulators, the TPS797xx requires an output capacitor connected between OUT and GND to stabilize the internal control loop. The minimum recommended capacitance is  $0.47-\mu F$ . Any  $0.47-\mu F$  capacitor is suitable, and capacitor values larger than  $0.47-\mu F$  are acceptable.

## 8.2.1.3 Application Curves

over operating temperature range  $T_J = -40^{\circ}\text{C}$  to 85°C, typical values are at  $T_A = 25^{\circ}\text{C}$ ,  $V_I = V_O$  (typical) + 0.5 V or 2 V (whichever is greater);  $I_O = 0.5$  mA,  $V_{EN} = V_I$ , and  $C_O = 1$   $\mu\text{F}$  (unless otherwise noted)





# Power-Supply Recommendations

The TPS797xx is designed to operate from an input voltage range between 1.8 V and 5.5 V. The input voltage range must provide adequate headroom for the device to have a regulated output. This input supply must be well regulated. If the input supply is noisy, additional input capacitors with low ESR can help improve the output noise performance.

# 10 Layout

## 10.1 Layout Guidelines

General guidelines for linear regulator designs are to place all circuit components on the same side of the circuit board and as near as practical to the respective LDO pin connections. Place ground return connections to the input and output capacitor, and to the LDO ground pin as close to each other as possible, connected by a wide, component-side, copper surface. The use of vias and long traces to create LDO circuit connections is strongly discouraged and negatively affects system performance.

## 10.2 Layout Example

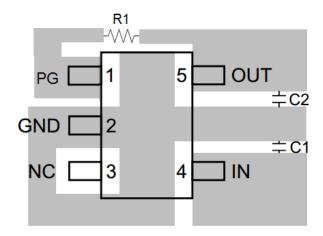


Figure 16. Layout Example

# 10.3 Power Dissipation and Junction Temperature

Specified regulator operation is ensured for a junction temperature of up to 85°C; restrict the maximum junction temperature to 85°C under normal operating conditions. This restriction limits the power dissipation the regulator can handle in any given application. To ensure the junction temperature is within acceptable limits, calculate the maximum allowable dissipation (P<sub>D(MAX)</sub>) and the actual dissipation (P<sub>D</sub>), which must be less than or equal to  $P_{D(MAX)}$ 

The maximum-power-dissipation limit is determined using Equation 1.

$$P_{D(max)} = \frac{T_{J}max - T_{A}}{R_{\theta JA}}$$

where

- T<sub>J(max)</sub> is the maximum allowable junction temperature
- R<sub>0,JA</sub> is the thermal resistance junction-to-ambient for the package (see *Thermal Information*)
- T<sub>A</sub> is the ambient temperature (1)

The regulator dissipation is calculated using Equation 2.

$$P_D = (V_I - V_O) \times I_O \tag{2}$$

Power dissipation resulting from quiescent current is negligible.

Submit Documentation Feedback



# 11 Device and Documentation Support

#### 11.1 Related Links

Table 3 lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

Table 3. Related Links

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
TPS79718	Click here	Click here	Click here	Click here	Click here
TPS797285	Click here	Click here	Click here	Click here	Click here
TPS79730	Click here	Click here	Click here	Click here	Click here
TPS79733	Click here	Click here	Click here	Click here	Click here

## 11.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

## 11.3 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E™ Online Community TI's Engineer-to-Engineer (E2E) Community. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

**Design Support** *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

#### 11.4 Trademarks

E2E is a trademark of Texas Instruments.

All other trademarks are the property of their respective owners.

## 11.5 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

## 11.6 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

# 12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

Copyright © 2001–2016, Texas Instruments Incorporated



www.ti.com 14-Oct-2022

#### **PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
TPS79718DCKR	ACTIVE	SC70	DCK	5	3000	RoHS & Green	NIPDAU   NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	ATD	Samples
TPS79718DCKT	ACTIVE	SC70	DCK	5	250	RoHS & Green	NIPDAU   NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	ATD	Samples
TPS79718DCKTG4	ACTIVE	SC70	DCK	5	250	RoHS & Green	NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	ATD	Samples
TPS797285DCKR	ACTIVE	SC70	DCK	5	3000	RoHS & Green	NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	OEB	Samples
TPS797285DCKT	ACTIVE	SC70	DCK	5	250	RoHS & Green	NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	OEB	Samples
TPS79730DCKR	ACTIVE	SC70	DCK	5	3000	RoHS & Green	NIPDAU   NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	ATE	Samples
TPS79730DCKRG4	ACTIVE	SC70	DCK	5	3000	RoHS & Green	NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	ATE	Samples
TPS79730DCKT	ACTIVE	SC70	DCK	5	250	RoHS & Green	NIPDAU   NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	ATE	Samples
TPS79733DCKR	ACTIVE	SC70	DCK	5	3000	RoHS & Green	NIPDAU   NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	ATF	Samples
TPS79733DCKT	ACTIVE	SC70	DCK	5	250	RoHS & Green	NIPDAU   NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	ATF	Samples
TPS79733DCKTG4	ACTIVE	SC70	DCK	5	250	RoHS & Green	NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	ATF	Samples

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

# PACKAGE OPTION ADDENDUM

www.ti.com 14-Oct-2022

- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

**Important Information and Disclaimer:** The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

#### OTHER QUALIFIED VERSIONS OF TPS797:

Automotive: TPS797-Q1

NOTE: Qualified Version Definitions:

Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects



www.ti.com 18-Nov-2024

# TAPE AND REEL INFORMATION



# TAPE DIMENSIONS + K0 - P1 - B0 W Cavity - A0 -

A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

## QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS79718DCKR	SC70	DCK	5	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
TPS79718DCKT	SC70	DCK	5	250	180.0	8.4	2.41	2.41	1.2	4.0	8.0	Q3
TPS79718DCKT	SC70	DCK	5	250	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
TPS797285DCKR	SC70	DCK	5	3000	180.0	8.4	2.41	2.41	1.2	4.0	8.0	Q3
TPS797285DCKT	SC70	DCK	5	250	180.0	8.4	2.47	2.3	1.25	4.0	8.0	Q3
TPS79730DCKR	SC70	DCK	5	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
TPS79730DCKR	SC70	DCK	5	3000	180.0	8.4	2.41	2.41	1.2	4.0	8.0	Q3
TPS79730DCKT	SC70	DCK	5	250	180.0	8.4	2.41	2.41	1.2	4.0	8.0	Q3
TPS79730DCKT	SC70	DCK	5	250	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
TPS79733DCKR	SC70	DCK	5	3000	180.0	8.4	2.41	2.41	1.2	4.0	8.0	Q3
TPS79733DCKR	SC70	DCK	5	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
TPS79733DCKT	SC70	DCK	5	250	180.0	8.4	2.41	2.41	1.2	4.0	8.0	Q3
TPS79733DCKT	SC70	DCK	5	250	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3



www.ti.com 18-Nov-2024



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS79718DCKR	SC70	DCK	5	3000	180.0	180.0	18.0
TPS79718DCKT	SC70	DCK	5	250	183.0	183.0	20.0
TPS79718DCKT	SC70	DCK	5	250	180.0	180.0	18.0
TPS797285DCKR	SC70	DCK	5	3000	183.0	183.0	20.0
TPS797285DCKT	SC70	DCK	5	250	183.0	183.0	20.0
TPS79730DCKR	SC70	DCK	5	3000	180.0	180.0	18.0
TPS79730DCKR	SC70	DCK	5	3000	183.0	183.0	20.0
TPS79730DCKT	SC70	DCK	5	250	183.0	183.0	20.0
TPS79730DCKT	SC70	DCK	5	250	180.0	180.0	18.0
TPS79733DCKR	SC70	DCK	5	3000	183.0	183.0	20.0
TPS79733DCKR	SC70	DCK	5	3000	180.0	180.0	18.0
TPS79733DCKT	SC70	DCK	5	250	183.0	183.0	20.0
TPS79733DCKT	SC70	DCK	5	250	180.0	180.0	18.0



SMALL OUTLINE TRANSISTOR



## NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
  2. This drawing is subject to change without notice.
  3. Reference JEDEC MO-203.

- 4. Support pin may differ or may not be present.5. Lead width does not comply with JEDEC.
- 6. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25mm per side



SMALL OUTLINE TRANSISTOR



NOTES: (continued)

7. Publication IPC-7351 may have alternate designs.8. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE TRANSISTOR



NOTES: (continued)

- 9. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 10. Board assembly site may have different recommendations for stencil design.



# IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2024, Texas Instruments Incorporated